



DMT10H072LFDF

D

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Product Summary

| BV _{DSS} | R _{DS(ON)} max | I _D max T _A = +25°C |
|-------------------|-----------------------------|----------------------------------------------|
| 1001/ | $62m\Omega @ V_{GS} = 10V$ | 4A |
| 100V | 80mΩ @ V _{GS} = 6V | 3.5A |

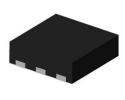
Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

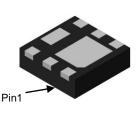
Applications

- **Power Management Functions**
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

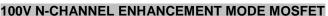
U-DFN2020-6 (Type F)



Top View



Bottom View

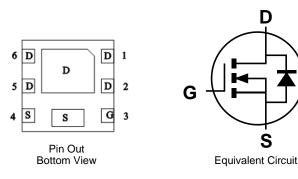


Features and Benefits

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low On-Resistance
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0065 grams (Approximate)



Ordering Information (Note 4)

| | Part Number | Case | Quantity Per Reel | | | | |
|--------|------------------------------------------------------------------------------------------------------------------------------|----------------------|-------------------|--|--|--|--|
| | DMT10H072LFDF-7 | U-DFN2020-6 (Type F) | 3,000 | | | | |
| | DMT10H072LFDF-13 | U-DFN2020-6 (Type F) | 10,000 | | | | |
| Notes: | tes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. | | | | | | |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

U-DFN2020-6 (Type F)



 $\begin{array}{l} 72 = \mbox{Product Type Marking Code} \\ \mbox{YM} = \mbox{Date Code Marking} \\ \mbox{Y} = \mbox{Year (ex: G = 2019)} \\ \mbox{M} = \mbox{Month (ex: 9 = September)} \end{array}$

| Date Code Key | | | - | | | | | | | | | |
|---------------|------|-----|-----|------|------|-----|-----|------|------|-----|-----|------|
| Year | 2019 | 20 |)20 | 2021 | 2022 | 20 | 023 | 2024 | 2025 | 20 | 026 | 2027 |
| Code | G | | Н | | J | | K | L | М | | Ν | 0 |
| Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |

U-DFN2020-6 (Type F)



72 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 9 = 2019)

W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal Code (ex: U = Monday)

| Date Code Key | | | | | | | | | |
|---------------|------|------|------|-------|------|------|------|------|------|
| Year | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 |
| Code | 9 | 0 | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
| | | | | | | | | | |
| Week | 1-26 | | | 27-52 | | | 53 | | |
| Code | A-Z | | | a-z | | | Z | | |
| | | | | | | | | | |
| Internal Code | Sun | Мо | n | Tue | Wed | Thu | | Fri | Sat |
| Code | Т | U | | V | W | Х | | Y | Z |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|----------------------------------------------------------|--------------------------------------------------|------------------|----------|----|
| Drain-Source Voltage | V _{DSS} | 100 | V | |
| Gate-Source Voltage | | V _{GSS} | ±20 | V |
| Continuous Drain Current, V _{GS} = 10V (Note 6) | T _A = +25°C T _A = +70°C | ID | 4 3.2 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | · | I _{DM} | 22 | А |
| Maximum Body Diode Continuous Current | | ls | 1.6 | А |
| Avalanche Current, L = 0.1mH (Note 9) | I _{AS} | 6 | А | |
| Avalanche Energy, L = 0.1mH (Note 9) | | E _{AS} | 1.8 | mJ |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit | |
|--------------------------------------------------|------------------------|-----------------------|-------------|------|--|
| Total Dower Dissinction (Note 5) | T _A = +25°C | D | 0.8 | 14/ | |
| Total Power Dissipation (Note 5) | T _A = +70°C | PD | 0.5 | W | |
| Thermal Resistance, Junction to Ambient (Note 5) | | $R_{	extsf{	heta}JA}$ | 149 | °C/W | |
| Total Dower Dissinction (Note 6) | T _A = +25°C | | 1.8 | W | |
| Total Power Dissipation (Note 6) | T _A = +70°C | PD | 1.1 | | |
| Thermal Resistance, Junction to Ambient (Note 6) | | $R_{\theta JA}$ | 71 | °C/W | |
| Thermal Resistance, Junction to Case (Note 6) | R _{0JC} | 13 | C/VV | | |
| Operating and Storage Temperature Range | | TJ, TSTG | -55 to +150 | °C | |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--------------------------------------------|---------------------|-----|------|------|-------|------------------------------------------------------------|--|
| OFF CHARACTERISTICS (Note 7) | Cymbol | | 176 | max | Unit | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 100 | — | _ | V | $V_{GS} = 0V, I_{D} = 250\mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | | 1 | μA | $V_{DS} = 80V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | — | _ | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | · | |
| Gate Threshold Voltage | V _{GS(TH)} | 1 | _ | 3 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| | | _ | 47 | 62 | mΩ | $V_{GS} = 10V, I_D = 4.5A$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | | 54 | 80 | 11122 | $V_{GS} = 6V, I_D = 4A$ | |
| | . , | _ | 64 | 110 | mΩ | $V_{GS} = 4.5V, I_D = 2.6A$ | |
| Diode Forward Voltage | V _{SD} | _ | 0.7 | 1.0 | V | $V_{GS} = 0V, I_{S} = 1A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | · | |
| Input Capacitance | Ciss | _ | 228 | _ | pF | | |
| Output Capacitance | Coss | _ | 89.3 | _ | pF | −V _{DS} = 50V, V _{GS} = 0V, −f = 1MHz | |
| Reverse Transfer Capacitance | Crss | _ | 2.5 | — | pF | | |
| Gate Resistance | Rg | _ | 8.2 | — | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 2.5 | — | nC | | |
| Total Gate Charge (V _{GS} = 10V) | Qg | _ | 4.5 | — | nC | | |
| Gate-Source Charge | Q _{gs} | _ | 0.6 | _ | nC | $V_{DS} = 50V, I_D = 4.5A$ | |
| Gate-Drain Charge | Q _{gd} | | 1.3 | _ | nC | 7 | |
| Turn-On Delay Time | t _{D(ON)} | — | 3.0 | — | ns | | |
| Turn-On Rise Time | t _R | — | 3.1 | — | ns | $V_{DS} = 50V, R_{L} = 11\Omega$ | |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 12.3 | _ | ns | $V_{GS} = 10V, R_{GEN} = 3\Omega$ | |
| Turn-Off Fall Time | t _F | | 4.3 | _ | ns | | |
| Reverse Recovery Time | t _{RR} | | 22.9 | _ | ns | | |
| Reverse Recovery Charge | Q _{RR} | | 45.2 | _ | nC | I _F = 4.5A, di/dt = 300A/µs | |

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. Short duration pulse test used to minimize self-heating effect.

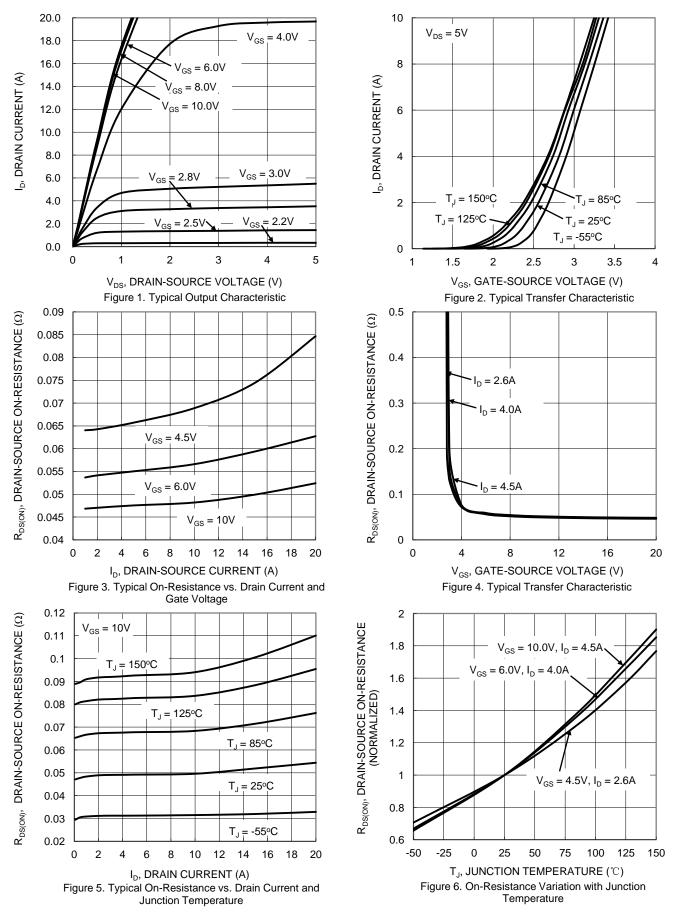
8. Guaranteed by design. Not subject to product testing.

9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

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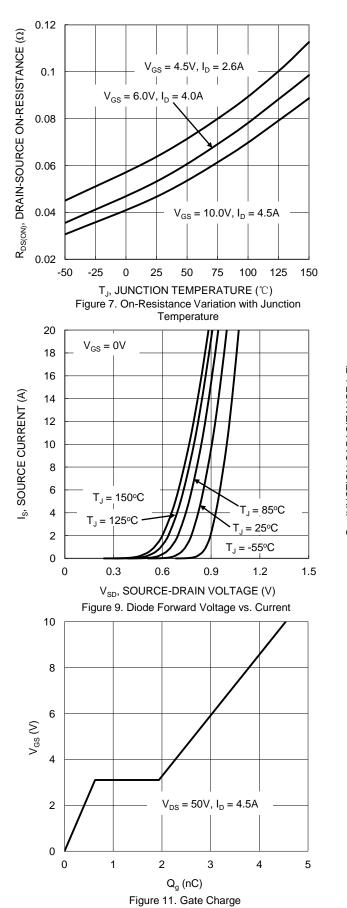
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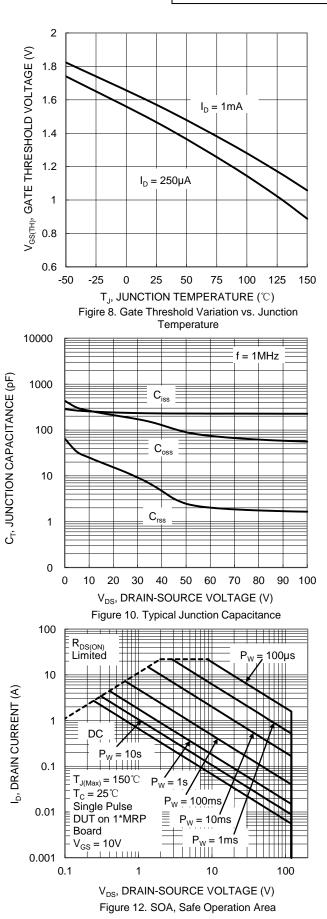


DMT10H072LFDF Datasheet number: DS38574 Rev. 5 - 2

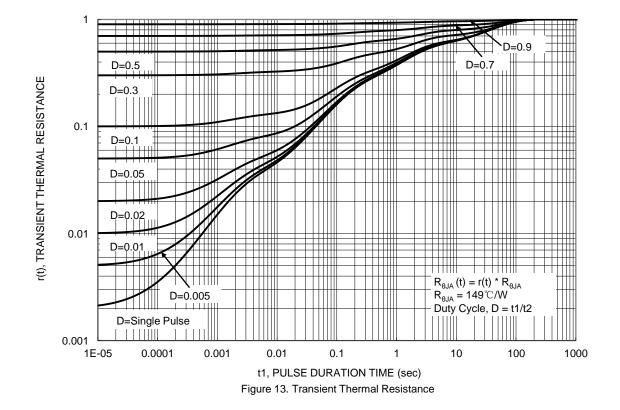
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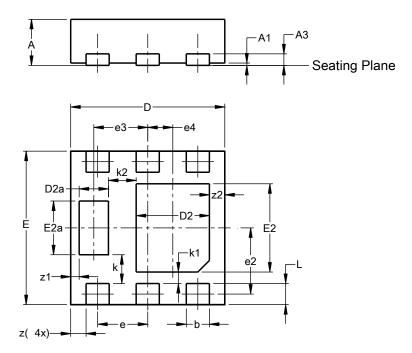




Package Outline Dimension

Please see http://www.diodes.com/package-outlines.html for the latest version.

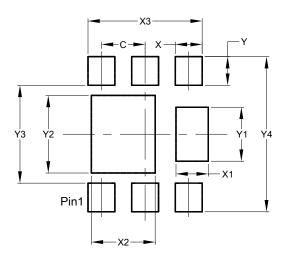
U-DFN2020-6 (Type F)



| | | 2020-6 | 1 | | | | | |
|----------|--------|----------|-------|--|--|--|--|--|
| (Type F) | | | | | | | | |
| Dim | Min | Max | Тур | | | | | |
| Α | 0.57 | 0.63 | 0.60 | | | | | |
| A1 | 0.00 | 0.05 | 0.03 | | | | | |
| A3 | - | - | 0.15 | | | | | |
| b | 0.25 | 0.35 | 0.30 | | | | | |
| D | 1.95 | 2.05 | 2.00 | | | | | |
| D2 | 0.85 | 1.05 | 0.95 | | | | | |
| D2a | 0.33 | 0.43 | 0.38 | | | | | |
| E | 1.95 | 2.05 | 2.00 | | | | | |
| E2 | 1.05 | 1.25 | 1.15 | | | | | |
| E2a | 0.65 | 0.75 | 0.70 | | | | | |
| е | | 0.65 BSC | | | | | | |
| e2 | 0 |).863 BS | SC | | | | | |
| e3 | | 0.70 BS | С | | | | | |
| e4 | 0 |).325 BS | SC | | | | | |
| k | | 0.37 BS | С | | | | | |
| k1 | | 0.15 BS | С | | | | | |
| k2 | | 0.36 BS | С | | | | | |
| L | 0.225 | 0.325 | 0.275 | | | | | |
| z | | 0.20 BS | С | | | | | |
| z1 | |).110 BS | | | | | | |
| z2 | | 0.20 BS | C | | | | | |
| All D | Dimens | ions in | mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-6 (Type F)

| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.650 |
| Х | 0.400 |
| X1 | 0.480 |
| X2 | 0.950 |
| X3 | 1.700 |
| Y | 0.425 |
| Y1 | 0.800 |
| Y2 | 1.150 |
| Y3 | 1.450 |
| Y4 | 2.300 |



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